

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S79	2	("4704300").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/03/17 14:31
S83	2	((fluorine (F near (atoms ions))) near concentration) same S82	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/17 14:51
S82	4370	S80 S81	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/17 14:51
S81	388	a-SiN "a-Si.sub"\$N. sub"\$4 "a - Si.sub"\$N. sub"\$4 "a- Si.sub"\$N. sub"\$4 "a -Si.sub"\$N. sub"\$4	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/17 14:51
S80	4093	amorphous near2 (SiN (silicon near nitride) "Si. sub"\$N.sub"\$4)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/17 14:51
S85	8	((fluorine (F near (atoms ions))) same concentration) same S82	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/17 15:14
S84	8	((fluorine (F near (atoms ions))) with concentration) same S82	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/17 15:14
S86	2	("20050223986").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/03/17 15:16
S89	55	S87 S88	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/17 15:19

S88	19	("20020117691" "20040127033" "20050223986" "4838652" "5712208" "5812284" "5834345" "5837614" "7095460" "7220991").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/17 15:19
S87	36	("20030066607" "20030097987" "20030124848" "20040039989" "20050233092" "20050251990" "20050255257" "4854263" "5439524" "6024799" "6040022" "6050506" "6106663" "6132512" "6454860" "6565661" "6823589" "6942753" "7052622" "7462564").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/17 15:19
S90	281	((fluorine (F near (atoms ions))) same concentration) same (SiN (silicon near nitride) "Si. sub"\$N.sub"\$4)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/17 15:24
S91	26	((fluorine (F near (atoms ions))) same concentration) same (SiN (silicon near nitride) "Si. sub"\$N.sub"\$4) same (gate near (dielectric insulat\$3))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/17 15:25
S94	27	((fluorine (F near (atoms ions))) and concentration) and (SiN (silicon near nitride) "Si.sub"\$N. sub"\$4) and (gate near (dielectric insulat\$3))).clm.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/18 13:21
S95	1116	(257/410).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/03/18 13:51
S96	3	("2005/0223986").URPN.	USPAT	OR	ON	2009/03/18 14:27
S97	166	S95 and (halogen fluorine)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/18 15:07

S98	32	("4772927" "4810673" "4894352" "4943837" "5013691" "5037766" "5275977" "5313075" "5313076" "5403772"). PN. OR ("5866932"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2009/03/18 15:13
L2	920	(257/57).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/03/19 05:36
L3	1105	(257/E21.625).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/03/19 05:41
L4	1176	(257/291).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/03/19 05:48
L6	951	(438/482).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/03/19 06:44
L7	2584	(438/197).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/03/19 06:46

3/19/2009 7:00:04 AM

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